



Local study of Lithium Niobate domain walls



Presenter name and spokesperson

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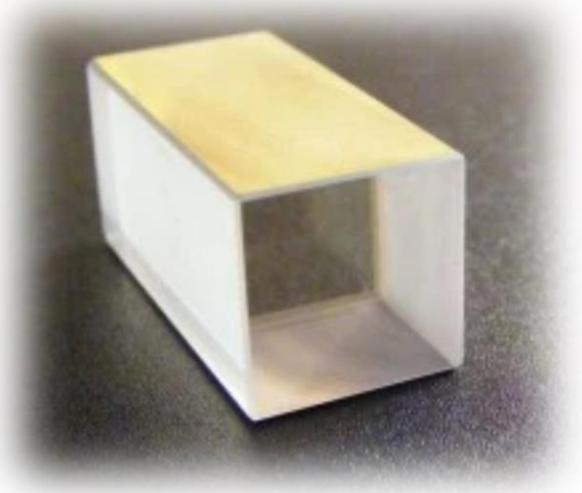
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Lithium Niobate

- Robust wide-band-gap ferroelectric ($E_g \approx 4 \text{ eV}$)
- High Curie temperature ($T_c \approx 1200 \text{ }^\circ\text{C}$)
- Large values of the spontaneous polarization near room temperature ($P_s \approx 70 \text{ } \mu\text{C/cm}^2$)
- The 5-%Mg doping level leads to a two-order higher optical stability



References:

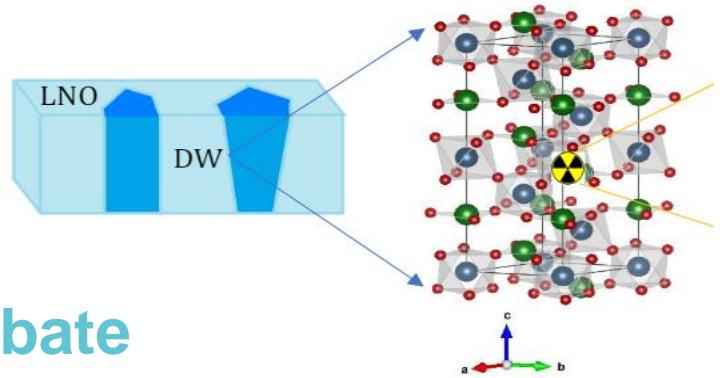
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Domain Walls (DW)

General

- Ferroelectric domain walls isolate regions with different polarizations.
- Due to the local breaking of spatial symmetry, DW can exhibit properties completely different from those of the material
- Charged ferroelectric domain walls (CDW) in LNO have a 13-order higher conductivity than in bulk.
- New applications: adaptive-optical elements, electrically controlled integrated-optical chips for quantum photonics, and advanced LN-semiconductor-hybrid optoelectronic devices

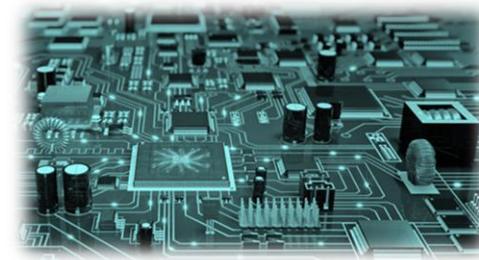


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Applications

current state of art and future



LNO in nanoelectronics

- Sensors in compact electromechanical systems
- Selectors in phase-change memory and resistive random access memory
- Half-wave/full wave rectifiers in modern nanocircuits.

The role of DW in performance

- Conduction through head-to-head, neutral or tail-to-tail DWs
- High conductivity between polarization orientations
- Ultra-thin topological interface (~few units cells)
- “DW electronics’

References:

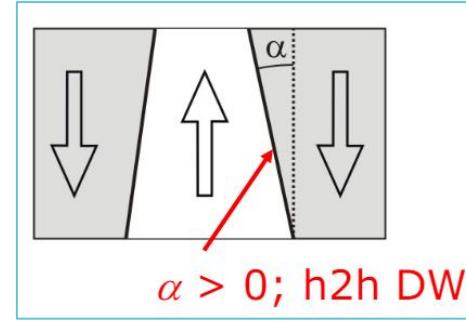
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Applications

current state of art and future

The role of DW in performance

- Inclined DWs ($\alpha > 0$) in LNO lead to DW conductivity (DWC) of up to 1 mA [Kirbus2019, Godau2017]
- h2h vs. t2t, i.e. n-type / p-type DWs in PPLN are re-configurable [Xiao2018]
- DWC transport activation energies (20 ... 400 °C of ~ 120 meV [Kämpfe2020, Yakhnevych2024]
- Bloch-, Néel-type DW topology in LNO [Acevedo-Salas2023]
- Hall-transport of inclined h2h DWs in LNO show 2D-electron-gas behavior [Beccard2024, Verhoff2024, Yakhnevych2024]
- Separating Schottky barrier injection from true electronic DW transport through the R2D2-model [Zahn2024]
- Enhanced DWC by photo-generated electron-hole pairs [Ding2024]
- Mechanical strain in-/decreases DWC depending on DW orientation [Singh2021]



Works of the group Prof. Lukas Eng (TU-Dresden)

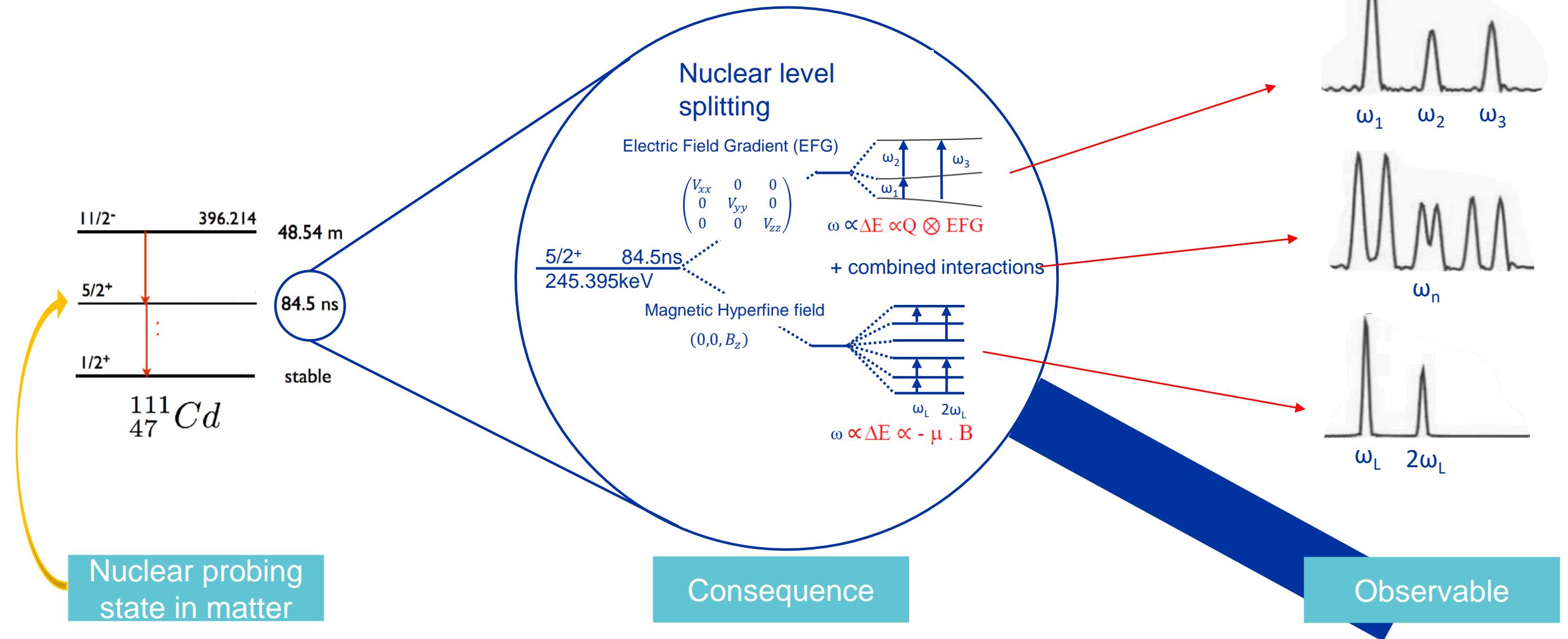
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Perturbed Angular Correlation (PAC)

A method to probe hyperfine interactions in matter



The frequencies

Quadrupole frequency: $\omega_Q = \frac{eQV_{zz}}{4I(2I-1)\hbar}$

Lowest observable transition frequency
for half-integer spin and $\eta = 0$:

$$\omega_0 = 6\omega_Q$$

$$\omega_n = n\omega_0 \text{ (} n = 1, 2, 3 \text{ for } I = 5/2 \text{)}$$

Spin independent: $v_Q = \frac{eQV_{zz}}{\hbar}$

For $\eta \neq 0$ and $I = 5/2$

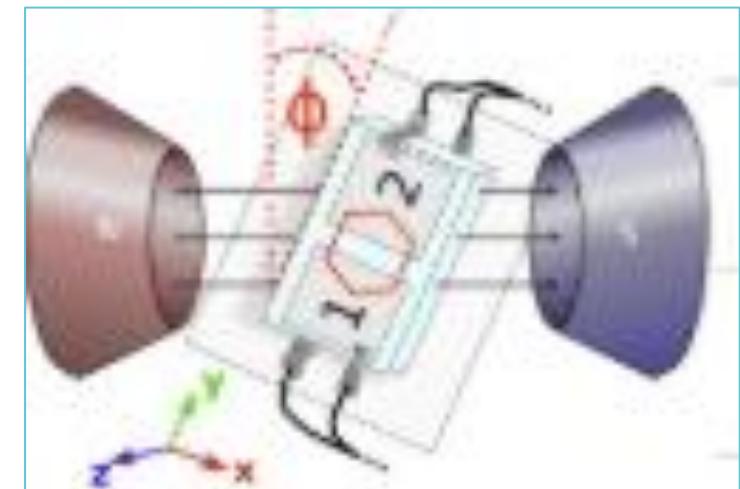
$$\omega_1 = 2\sqrt{3}\alpha\omega_q \sin\left(\frac{1}{3}\arccos(\beta)\right),$$

$$\omega_2 = 2\sqrt{3}\alpha\omega_q \sin\left(\frac{1}{3}[\pi - \arccos(\beta)]\right),$$

$$\omega_3 = 2\sqrt{3}\alpha\omega_q \sin\left(\frac{1}{3}[\pi + \arccos(\beta)]\right),$$

$$\alpha = \sqrt{\frac{28(3 + \eta^2)}{3}},$$

$$\beta = \frac{80(1 - \eta^2)}{\alpha^3}.$$



The EFG in LNO

LNO properties



Nuclear probe properties

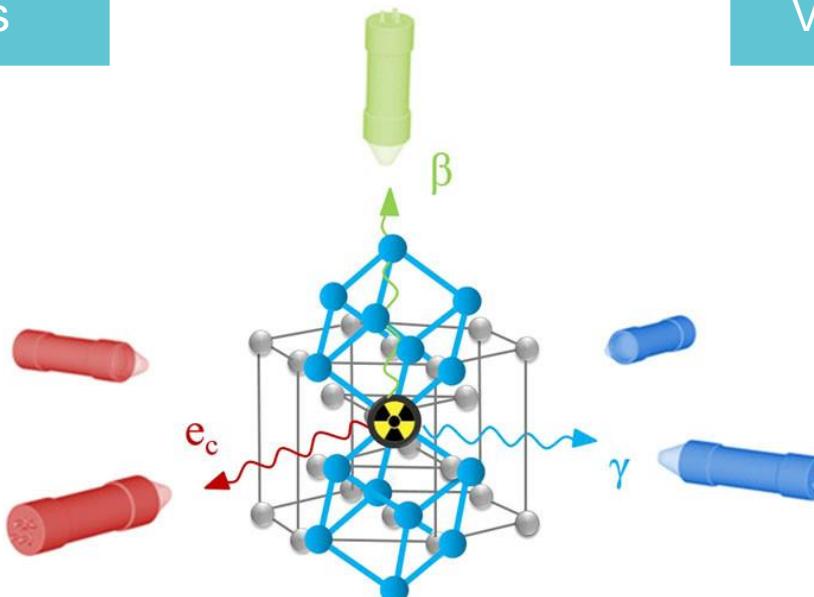


Nuclear probe incorporation method and measurements conditions

Apply fields

Conduction electrons (DWs)

Defects and lattice deformation



AIP Advances 7, 105017 (2017)
<https://doi.org/10.1063/1.4994249>

Vzz and η values

Electrons bound to the probe

Lattice location of the probe

Previous TDPAC measurements

^{111m}Cd implanted in LNO at 60 keV (ISOLDE)

Figure source: B. Hauer et al. Phys. Rev. B 51, 6208 (1995).

TABLE II. Values of the quadrupole interaction of ^{111}Cd in undoped and Mg-doped LiNbO_3 as derived from a least-squares fit to the data. The η values have been kept fixed to the ones given in Table I.

	$^{111m}\text{Cd} (^{111}\text{Cd})$	v_Q (MHz)	η	δ	f
Mg doped	Site 1	191(2)	0.11	0.035(5)	0.68(5)
	Site 2	204(2)	0.16	0.035(5)	0.32(5)
	Site 1	192(2)	0.11	0.027(5)	0.71(5)
Undoped	Site 2	205(2)	0.16	0.038(5)	0.29(5)

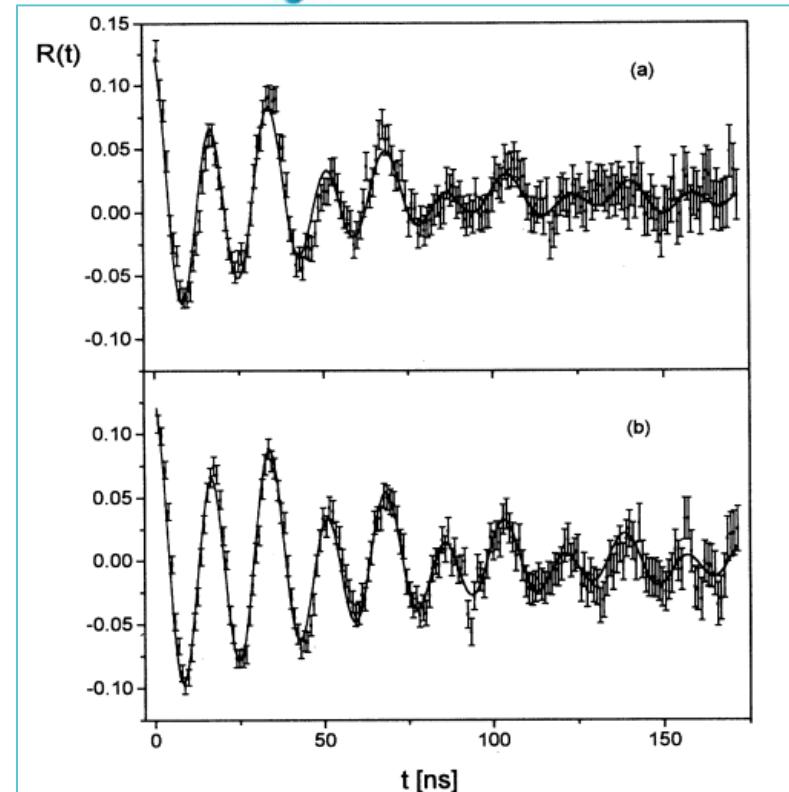
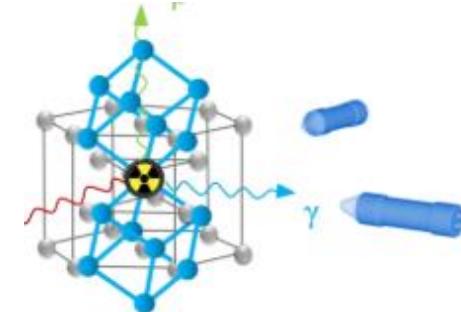


FIG. 6. Time-dependent anisotropy of the 151–245 keV $\gamma\gamma$ cascade of $^{111}\text{Cd}(^{111}\text{Cd})$ after annealing for 30 min at 970 K in Mg-doped (a) and undoped LiNbO_3 (b).

Previous TDPAC measurements

^{111}In implanted in LNO at 150 keV

Figure source: B. Hauer et al. Phys. Rev. B 51, 6208 (1995).

$v_{Q1} = 192(1)$ MHz and asymmetry parameter $\eta = 0.11(2)$ (predominant 68%) and $v_{Q1} = 205(1)$ MHz and $\eta = 0.16(4)$.

Second fraction for In@Li associated to a Nb-vacancy.

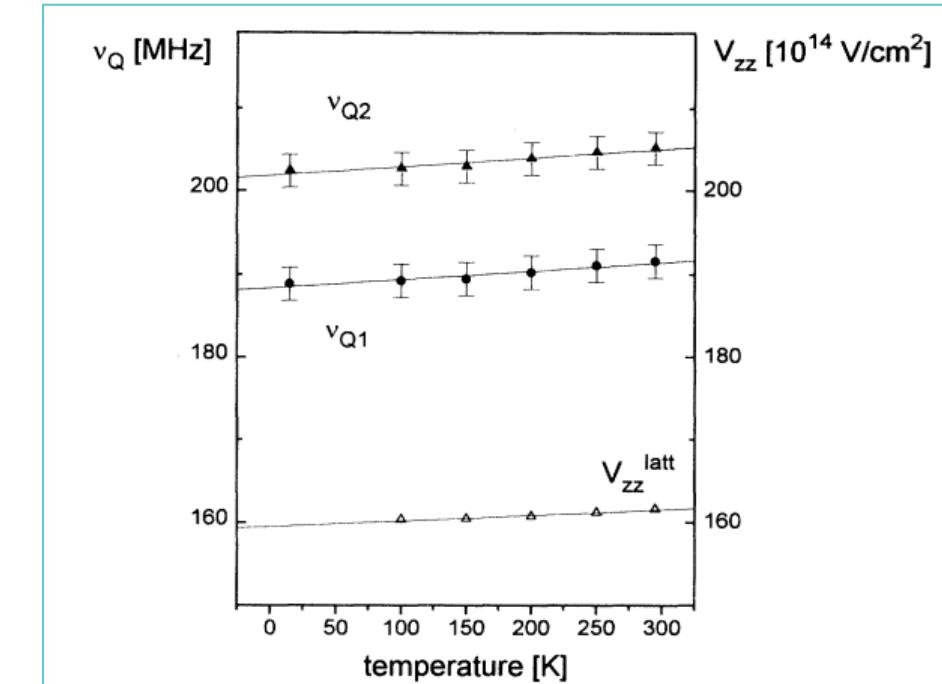
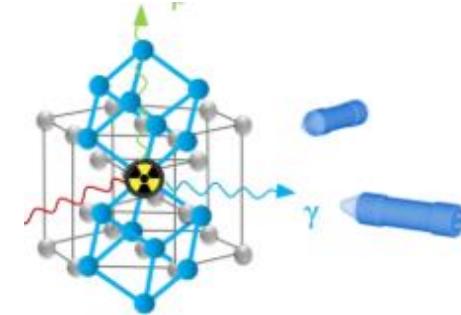


FIG. 5. Variation of v_{Q1} and v_{Q2} with the sample temperature. For comparison the EFG value V_{zz}^{latt} calculated in the point charge model (see text) for the corresponding lattice parameters is shown in the lower part.

Activ

Previous TDPAC measurements

Obtained NQI for ^{111m}Cd 60 keV at ISOLDE

Figure source: A. Kling, et al., Nucl. Instr. Meth. B 1996, 113, 293–295. [https://doi.org/10.1016/0168-583X\(95\)01329-6](https://doi.org/10.1016/0168-583X(95)01329-6)

$v_Q = 191(2)$ MHz and asymmetry parameter $\eta = 0$. The asymmetry parameter indicate a higher crystal lattice.

Other references: LN (4.6 wt% K₂O)

A. Kling, J.G. Marques, Crystals 2021, 11, 501.

<https://doi.org/10.3390/crust1105050>

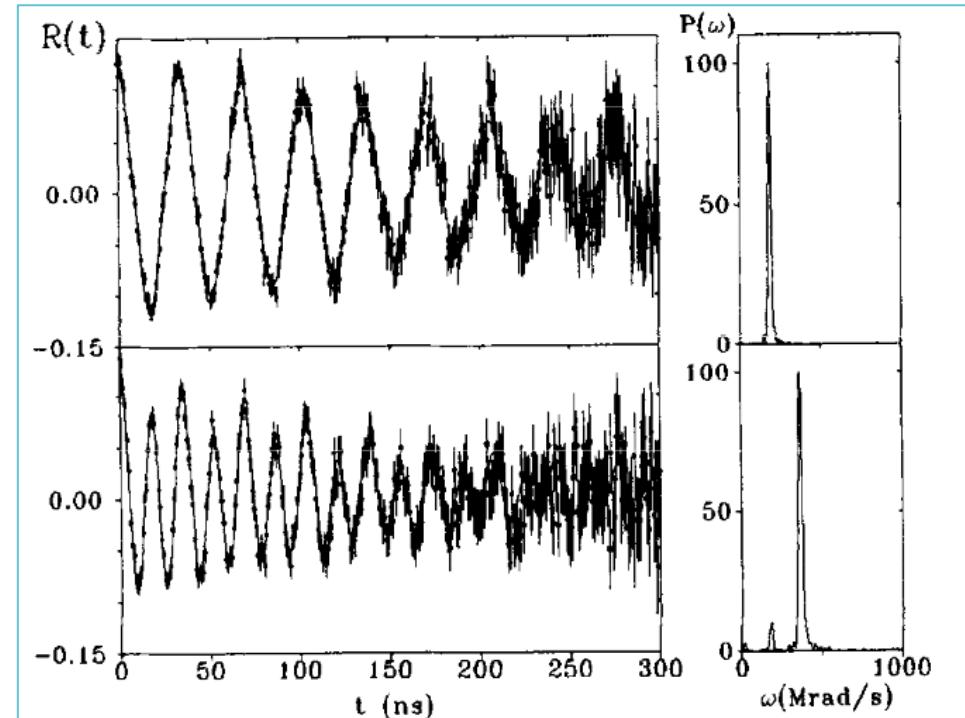


Fig. 4. Time dependent anisotropy of the 151–245 keV $e^- - \gamma$ cascade of ^{111}Cd in near-stoichiometric LiNbO₃, with c-axis perpendicular to the detectors' plane (top), and c-axis in the detectors' plane at 45° with two detectors (bottom).

Previous TDPAC measurements

Obtained NQI for ^{111}In 150 keV at HISKP

Figure source: J.G. Marques, et al., Rad. Eff. Def. Solids 1999, 150, 233–236.
<https://doi.org/10.1080/10420159908226235>

$\nu_{Q1} = 191(2)$ MHz and $\nu_{Q2} = 205.2$ MHz and asymmetry parameter $\eta > 0$. Two distinct Li-sites. Lattice disorder decreases with increase of K_2O (lower delta value).

Data could not be described by models that consider vacancies and Nb antisites.

Other references: LN (4.6 wt% K₂O)

A. Kling, J.G. Marques, Crystals 2021, 11, 501.

<https://doi.org/10.3390/crust1105050>

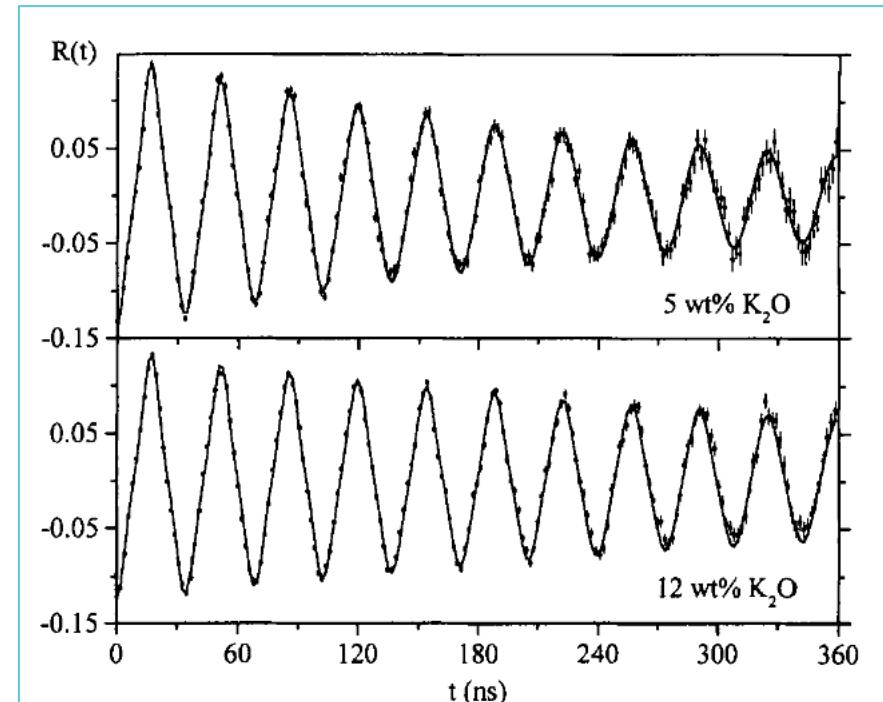
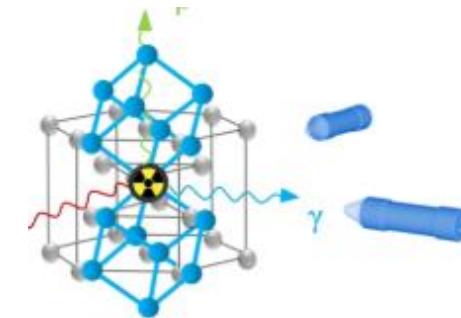
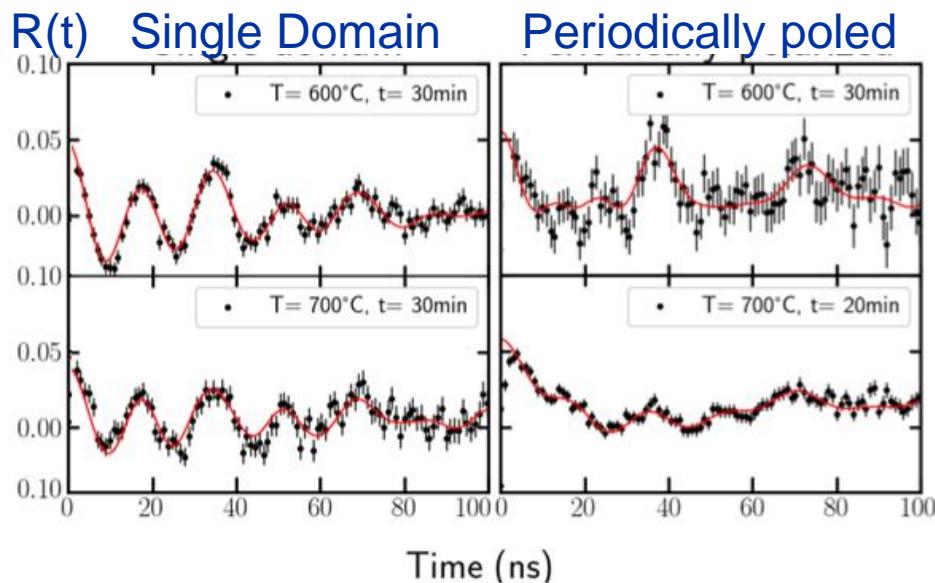


FIGURE 1 PAC spectra obtained in the K5 and K12 crystals.

Our TDPAC measurements

Spectra



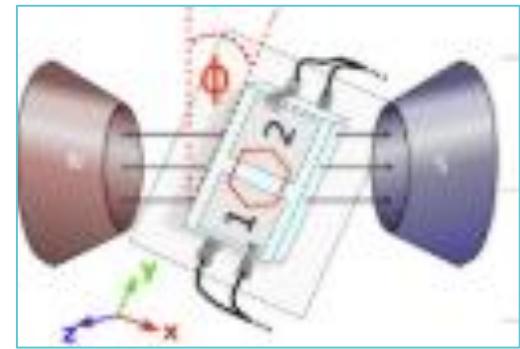
Comparison with DFT and previous work

System	Charge of System	$V_{33}^{\text{DFT}}(\text{V}/\text{A}^2)$	η^{DFT}	$\Delta H^{\text{DFT}}(\text{eV})$	$\omega_0^{\text{DFT}}[\text{Mrad}/\text{s}]$
CdLi	+1	90.956	0.000	-1.9529	172(1)
CdLi	0	89.243	0.000	4.8395	168(1)
CdLi with Li vacancy	0	91.726	0.106	8.5434	173(1)
		$V_{33}^{\text{Exp}}(\text{V}/\text{A}^2)$	η^{Exp}		$\omega_0^{\text{Exp}}[\text{Mrad}/\text{s}]$
Present study (Single domain, $T = 600^\circ\text{C}$)	-	95.3(4)	0	-	180.4(7)
Present study (Single domain, $T = 700^\circ\text{C}$)	-	96.2(1)	0	-	182(1)
[20] site 1	-	93.9(1)	0.11(2)	-	180(1)
[20] site 2	-	98.8(2)	0.16(4)	-	192(1)

Table 1: Relevant parameters for the Cd(LNO) calculation (^{DFT}) and experimental values (^{Exp}). Note that the reported values in $\Delta H^{\text{DFT}}(\text{eV})$ are taken with reference to the equivalent LNO supercell system without any defects.

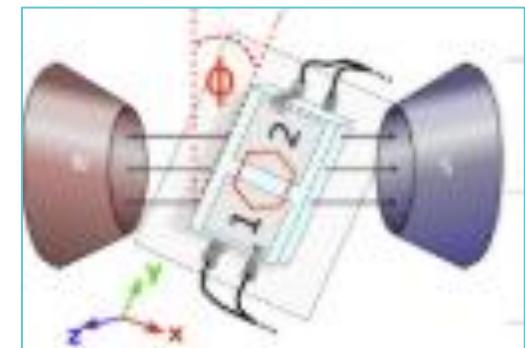
Beam request ^{111m}Cd 9 shifts (72 hours) + 1 shift reserved

Probe	Annealing	Number of samples (5 angular dependence measurements + reproduction)	Beam time
Single domain 30 keV (repeat for 60 keV)	air	10 +10	10 hours
	Oxygen flow	10 +10	10 hours
	Ar flow	10 +10	10 hours
Periodically poled 30 keV (repeat for 60 keV)	air	10 +10	10 hours
	Oxygen flow	10 +10	10 hours
	Ar flow	10 +10	10 hours
Single domain 30 keV applied E field (repeat for 60 keV)	air	2 +2	2 hours
	Oxygen flow	2 +2	2 hours
	Ar flow	2 +2	2 hours
Periodically poled 30 keV applied E field (repeat for 60 keV)	air	2 +2	2 hours
	Oxygen flow	2 +2	2 hours
	Ar flow	2 +2	2 hours



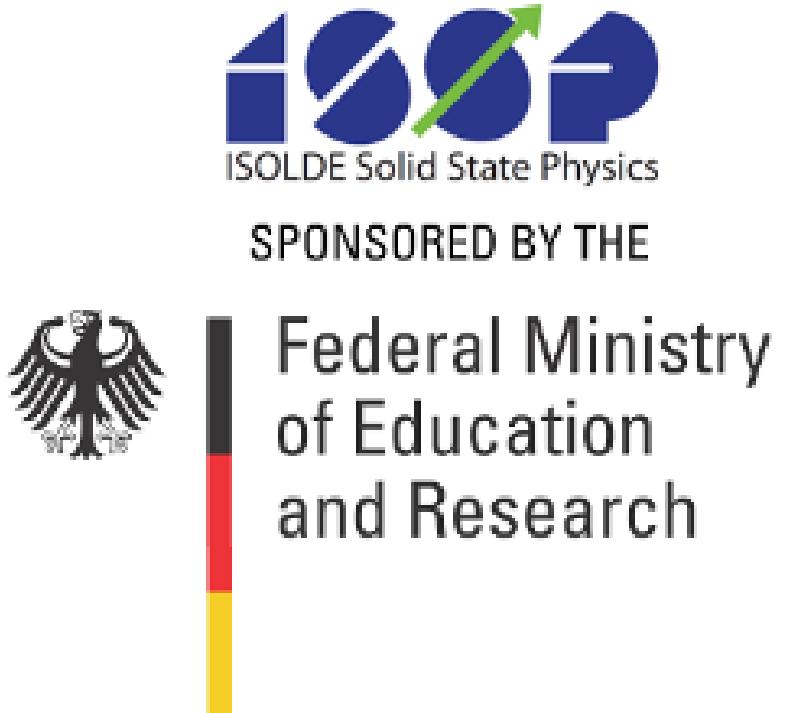
Beam request ^{111}In 2 shifts

Probe	Annealing	Number of samples (~10 angular dependence measurements + reproduction)	Beam time
Single domain 30 keV (repeat for 60 keV)	air	1 +1	2 hours
	Oxygen flow	1 +1	2 hours
	Ar flow	1 +1	2 hours
Periodically poled 30 keV (repeat for 60 keV)	air	1 +1	2 hours
	Oxygen flow	1 +1	2 hours
	Ar flow	1 +1	2 hours
Single domain 30 keV applied E field (repeat for 60 keV)	air	1 +1	2 hours
	Oxygen flow		
	Ar flow		
Periodically poled 30 keV applied E field (repeat for 60 keV)	air	1 +1	2 hours
	Oxygen flow		
	Ar flow		



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Master candidate

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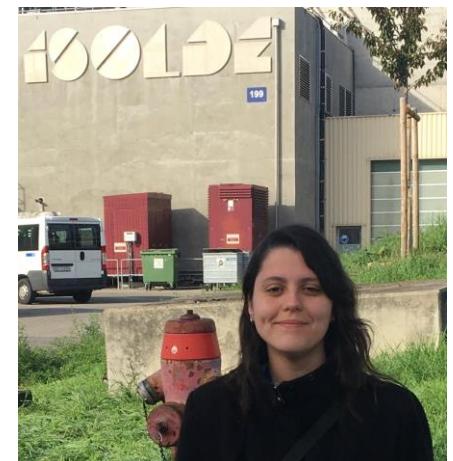
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- B. P. Rocha-Rodrigues



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